

Atty. Docket No. 8013-1036

PATENTS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Naoki FURUHATA

Confirmation No. 6317

Serial No. 09/848,263

GROUP 2823

Filed May 4, 2001

Examiner W. Coleman

MONOLITHIC COMPOUND SEMICONDUCTOR INTEGRATED CIRCUIT AND METHOD OF FORMING THE SAME

AMENDMENT

Commissioner for Patents

Washington, D.C. 20231

Sir:

Responsive to the Official Action of June 14, 2002, please amend the above-identified application as follows:

ABSTRACT OF THE DISCLOSURE:

Rewrite the Abstract of the Disclosure as on the accompanying separate sheet.

IN THE SPECIFICATION:

Page 2, replace the paragraph beginning on line ${\bf 5}$ as follows:

--Japanese laid-open patent publication No. 10-107042 discloses a conventional monolithic microwave integrated circuit. Such a conventional integrated circuit has the following problems. The hetero-junction bipolar transistor and the metal insulator metal capacitor are separately formed using separate



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